



LH0132, LH0132C

Ultra-Fast FET-Input Operational Amplifier

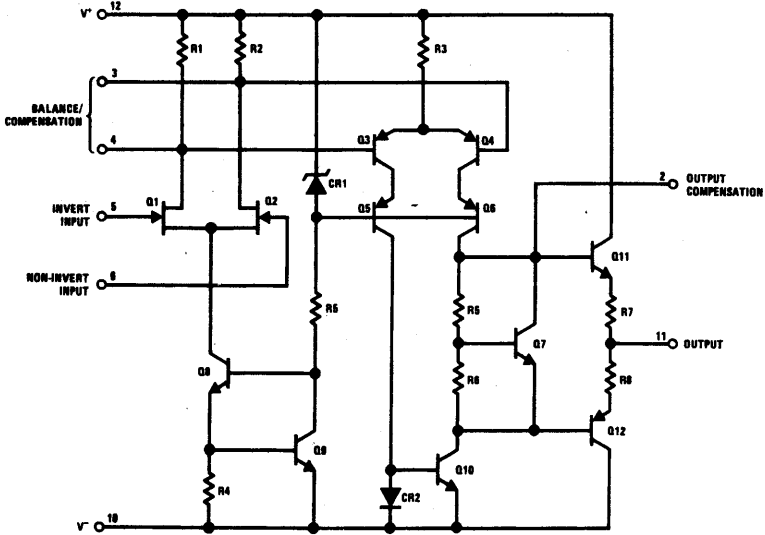
General Description

The LH0132 is a high slew rate, high input impedance differential amplifier. It was developed specifically for sample and hold and other fast signal handling applications which require very low input currents over the full input voltage range. Input offset and bias currents are guaranteed over a full input common mode range of -10 volts to +10 volts.

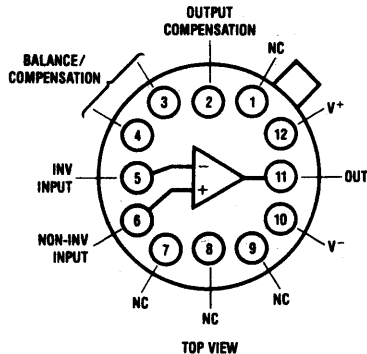
Features

- 600 pA I_{bias} at $V_{IN} = \pm 10V$
- 500 V/ μs slew rate
- 70 MHz bandwidth
- 5 mV offset voltage
- FET input
- No compensation for gains above 50
- Peak output current to 100 mA

Block and Connection Diagrams



TL/K/5499-4



TL/K/5499-5

Order Number LH0132G or LH0132CG
See NS Package H12B

Absolute Maximum Ratings

Supply Voltage, V_S	$\pm 18V$	Operating Temperature Range, T_A	LH0132G/AG	$-55^{\circ}C$ to $+125^{\circ}C$
Input Voltage, V_{IN}	$\pm V_S$		LH0132CG/ACG	$-25^{\circ}C$ to $+85^{\circ}C$
Differential Input Voltage	$\pm 30V$ or $\pm 2V_S$	Operating Junction Temperature, T_J		$175^{\circ}C$
Power Dissipation, P_D		Storage Temperature Range		$-65^{\circ}C$ to $+150^{\circ}C$
$T_A = 25^{\circ}C$	1.5W, derate $100^{\circ}C/W$ to $125^{\circ}C$ (Note 1)	Lead Temperature (Soldering, 10 seconds)		$300^{\circ}C$
$T_C = 25^{\circ}C$	2.2W, derate $70^{\circ}C/W$ to $125^{\circ}C$ (Note 1)			

DC Electrical Characteristics $V_S = \pm 15V, T_{MIN} \leq T_A \leq T_{MAX}$ unless otherwise noted (Note 2)

Parameter		Test Conditions		LH0132G			LH0132CG			Units
				Min.	Typ.	Max.	Min.	Typ.	Max.	
V_{OS}	Input Offset Voltage	$V_{IN} = 0$	$T_A = T_J = 25^{\circ}C$ (Note 3)		2	5		2	10	mV
$\Delta V_{OS\Delta T}$	Average Offset Voltage Drift		(Note 4)		25	50		25	50	$\mu V/^{\circ}C$
I_{OS}	Input Offset Current	$-10V \leq I_{IN} \leq 10V$	$T_J = 25^{\circ}C$ (Note 3)			15			30	pA
			$T_A = 25^{\circ}C$ (Note 5)				150			300
			$T_J = T_A = T_{MAX}$			15			5	nA
I_B	Input Bias Current		$T_J = 25^{\circ}C$ (Note 3)			75			150	pA
			$T_A = 25^{\circ}C$ (Note 5)			1			5	nA
			$T_J = T_A = T_{MAX}$			25			15	nA
$^*V_{INCM}$	Input Voltage Range			± 10	± 12		± 10	± 12		V
CMRR	Common Mode Rejection Ratio	$\Delta V_{IN} = \pm 10V$		50	60		45	60		dB
A_{VOL}	Open-Loop Voltage Gain	$V_O = \pm 10V$ $R_L = 1k\Omega$	$f = 70KHZ$ $T_J = 25^{\circ}C$ (Note 6)	60	70		50	70		dB
V_O	Output Voltage Swing	$R_L = 1k\Omega$		± 10	± 13.5		± 10	± 13		V
I_S	Power Supply Current	$T_J = 25^{\circ}C, I_O = 0$	(Note 6)		18	20		20	22	mA
PSRR	Power Supply Rejection Ratio	$AV_S = 10V$	$(\pm 5$ to $\pm 15)$	50	60		45	60		dB

AC Electrical Characteristics $V_S = \pm 15V, R_L = 1k\Omega, T_J = 25^{\circ}C$ (Note 7)

Parameter		Conditions		Min.	Typ.	Max.	Units
S_R	Slew Rate	$A_V = +1$	$\Delta V_{IN} = 20V$	350	500		$V/\mu S$
t_s	Settling Time to 1% of Final Value	$A_V = -1,$			100		ns
t_s	Settling Time to 0.1% of Final Value				300		ns
t_{R}	Small Signal Rise Time	$A_V = +1, \Delta V_{IN} = 1V$			8	20	ns
t_D	Small Signal Delay Time				10	25	ns

Note 1. In order to limit maximum junction temperature to $+175^{\circ}C$, it may be necessary to operate with $V_S < \pm 15V$ when T_A or T_C exceeds specific values depending on the P_D within the device package. Total P_D is the sum of quiescent and load-related dissipation. See Applications Notes AN-277, "Applications of Wide-Band Buffer Amplifiers" and AN-253, "High-Speed Operational-Amplifier Applications" for a discussion of load-related power dissipation.

Note 2. LH0132G is 100% production tested as specified at $25^{\circ}C, 150^{\circ}C$, and $-55^{\circ}C$. LH0132CG is 100% production tested at $25^{\circ}C$ only. Specifications at temperature extremes are verified by sample testing, but these limits are not used to calculate outgoing quality level.

Note 3. Specification is at $25^{\circ}C$ junction temperature due to requirements of high-speed automatic testing. Actual values at operating temperature will exceed the value at $T_J = 25^{\circ}C$. When supply voltages are $\pm 15V$, no-load operating junction temperature may rise $40-60^{\circ}C$ above ambient, and more under load conditions. Accordingly, V_{OS} may change one to several mV, and I_B and I_{OS} will change significantly during warm-up. Refer to I_B and I_{OS} vs. temperature graph for expected values.

Note 4. LH0132G is 100% production tested for this parameter. LH0132CG is sample tested only. Limits are not used to calculate outgoing quality levels. $\Delta V_{OS}/\Delta T$ is the average value calculated from measurements at $25^{\circ}C$ and T_{MAX} .

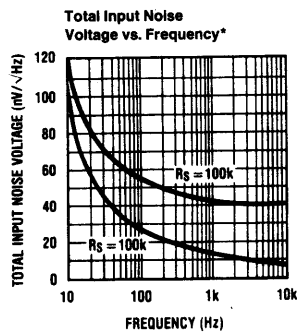
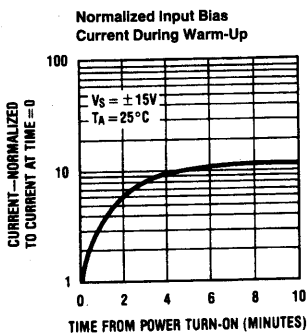
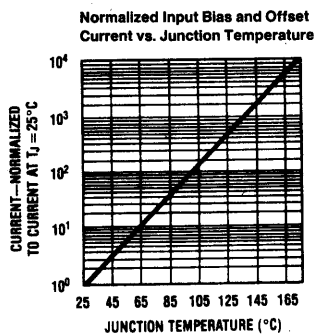
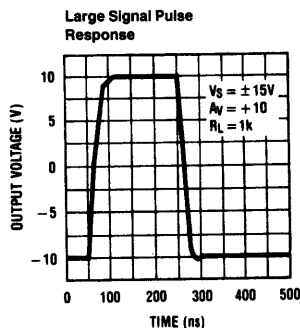
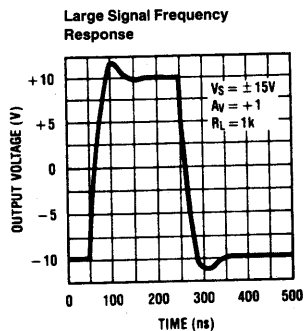
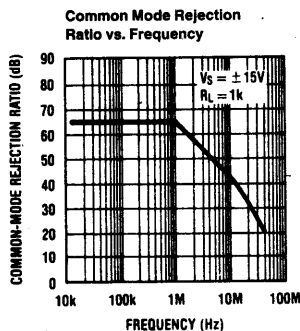
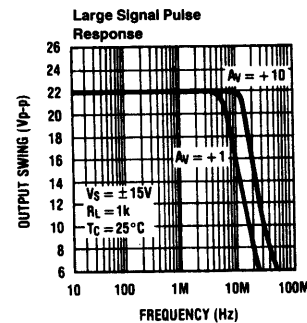
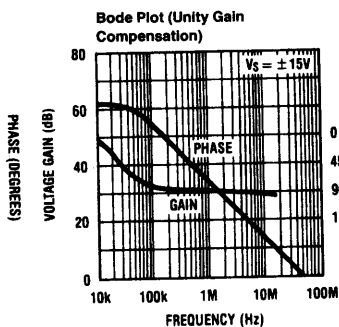
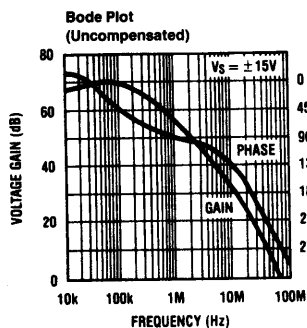
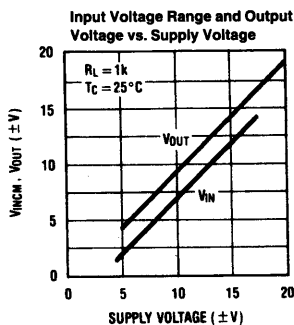
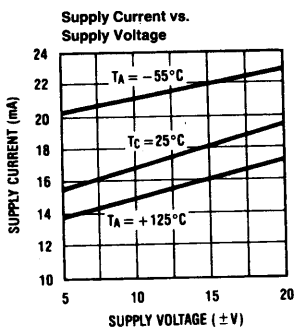
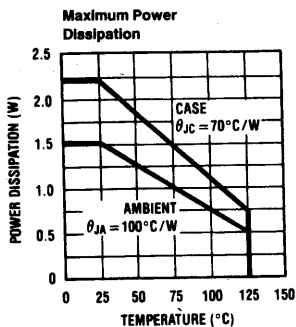
Note 5. Measured in still air 7 minutes after application of power. Guaranteed thru correlated automatic pulse testing.

Note 6. Guaranteed thru correlated automatic pulse testing at $T_J = 25^{\circ}C$.

Note 7. Not 100% production tested; verified by sample testing only. Limits are not used to calculate outgoing quality level.

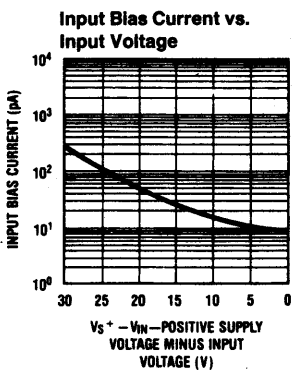
* Limits at high/low temp. are sample tested to LTPD = 10 on LH0132CG/ACG.

Typical Performance Characteristics



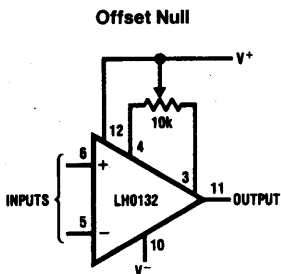
Typical Performance Characteristics (Continued)

Auxiliary Circuits

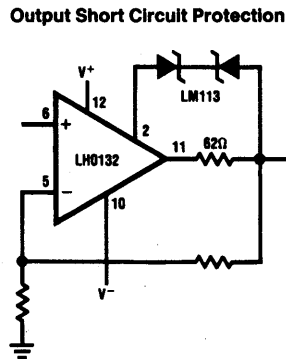


TL/K/5499-7

*Noise voltage includes contribution from source resistance.



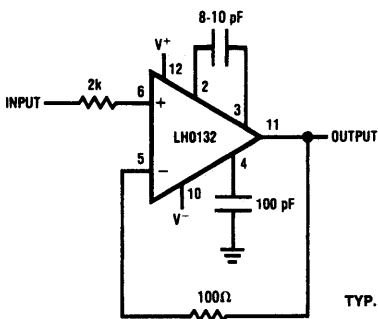
TL/K/5499-8



TL/K/5499-9

Typical Applications

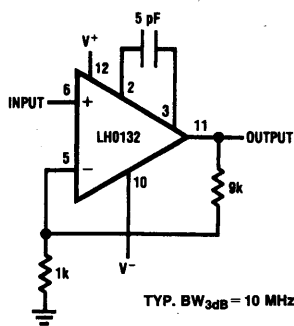
Unity Gain Amplifier



TYP. BW_{3dB} = 45 MHz

TL/K/5499-1

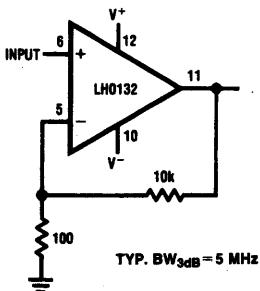
10X Buffer Amplifier



TYP. BW_{3dB} = 10 MHz

TL/K/5499-10

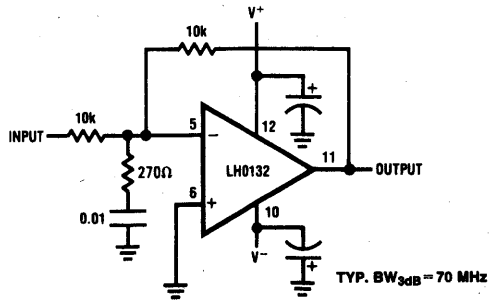
100X Buffer Amplifier



TYP. BW_{3dB} = 5 MHz

TL/K/5499-11

Non-Compensated Unity Gain Inverter



TYP. BW_{3dB} = 70 MHz

TL/K/5499-2